

CD4060B Types

CMOS 14-Stage Ripple-Carry Binary Counter/Divider and Oscillator

High-Voltage Types (20-Volt Rating)

■CD4060B consists of an oscillator section and 14 ripple-carry binary counter stages. The oscillator configuration allows design of either RC or crystal oscillator circuits. A RESET input is provided which resets the counter to the all-O's state and disables the oscillator. A high level on the RESET line accomplishes the reset function. All counter stages are master-slave flip-flops. The state of the counter is advanced one step in binary order on the negative transition of φ_{I} (and ϕ_0). All inputs and outputs are fully buffered. Schmitt trigger action on the line permits input-pulse input-pulse rise and fall times.

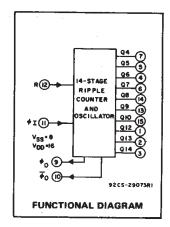
The CD4060B-series types are supplied in 16-lead hermetic dual-in-line ceramic packages (F3A suffix), 16-lead dual-in-line plastic packages (E suffix), 16-lead small-outline packages (M, M96, MT, and NSR suffixes), and 16-lead thin shrink small-outline packages (PW and PWR suffixes).

Features:

- m 12 MHz clock rate at 15 V
- **■** Common reset
- Fully static operation
- Buffered inputs and outputs
- Schmitt trigger input-pulse line
- 100% tested for quiescent current at 20 V
- Standardized, symmetrical output characteristics
- 5-V, 10-V, and 15-V parametric ratings
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for description of "B" Series CMOS Devices"

Oscillator Features:

- All active components on chip
- RC or crystal oscillator configuration
- RC oscillator frequency of 690 kHz min. at 15 V



Applications

- Control counters
- Timers
- Frequency dividers
- Time-delay circuits

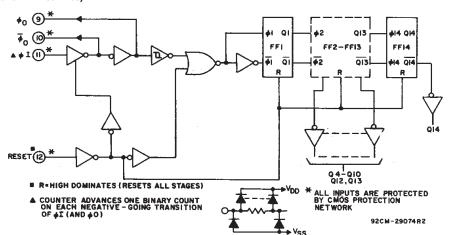


Fig.1 - Logic diagram.

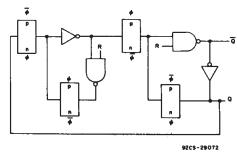
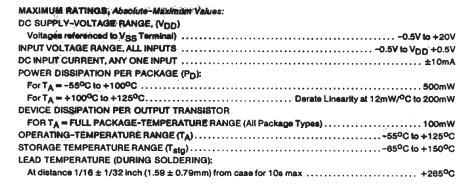


Fig. 2 — Detail of typical flip-flop stage.



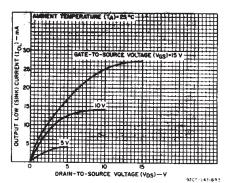


Fig. 3 — Typical n-channel output low (sink) current characteristics.

CD4060B Types

CHARAC- TERISTIC	CON	DITIO	NS	LIM	ITS AT II		ED TEM	PERATU		C)	UNIT
	vo	VIN	V _{DD}				E #		+25		s
	(V)	(v)	(8)	-55	-40	+85	+125	Min.	Тур.	Max.	
Quiescent	_	0,5	5	5	-5	150	150		0.04	5	Г
Device		0,10	10	10	10	300	300		0.04	10	μı
Current,		0,15	15	20	20	600	600	1991 1	0.04	20	
IDD Max.	_	0,20	20	100	100	3000	3000	_	0.08	100	
Output Low	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1 .	-	
(Sink)Ourrent*,	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6		
IOL Min.	1.5	0,15	15	4.2	4	2.8	2.4.	3.4	6.8	_	
Outout High	4.6	0,5	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	-	m
Output High (Source) Current*, IOH Min.	2.5	0,5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	-	
	9.5	0,10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	-	
IOH MIIII.	13.5	0,15	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8		
Output Voltage:	. -	0,5	5		0	.05		-	0	0.05	Г
Low-Level,	1 11.4	0,10	10		0	_	0	0.05	1		
VOL Max.		0,15	15		0.	_	0	0.05	v		
Output		0,5	5		4.	95		4.95	. 5	_	1
Voltage:	-	0,10	10		9.	.95		9.95		_	
High-Level, VOH Min.	-	0,15	15		14.	.95		14.95	15	-	
Input Low	0.5,4.5	_	5			1.5	-	_		1.5	┢
Voltage	1,9	-	10			3		_		3	١
VIL Max.	1.5,13.5	_	15			4	:	-		4	١,
Input High	0.5,4.5	_	5		:	3.5		3.5	-	-	1
Voltage,	1,9	_	10			7		7	-	-	1
V _{IH} Min.	1.5,13.5	ı	15			11		11		-	1
Input Current I _{IN} Max.	-	0,18	18	±0.1	±0.1	±1	.±1 . ,	_	±10 ⁻⁵	±0.1	μ

^{*}Data not applicable to terminal 9 or 10.

RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges

CHARACTERISTIC	v_{DD}	LII	UNITS	
And the second second	100	MIN.	MAX.	
Supply-Voltage Range (For T _A = Full Package Temperature Range)	-	3	18	٧
Input-Pulse Width, t _W (f = 100 kHz)	5 10 15	100 40 30	- - -	ns
Input-Pulse Rise Time and Fall Time, $t_{r\phi}$, $t_{f\phi}$	5 10 15	Unli	mited	
Input-Pulse Frequency, $f_{\phi \underline{\mathbf{I}}}$ (External pulse source)	5 10 15	— — —	3.5 8 12	MHz
Reset Pulse Width, t _W	5 10 15	120 60 40	<u>-</u> -	ns

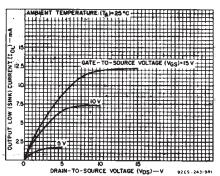


Fig. 4 — Minimum n-channel output low (sink) current characteristics.

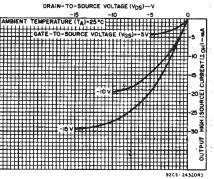


Fig. 5 — Typical p-channel output high (source) current characteristics.

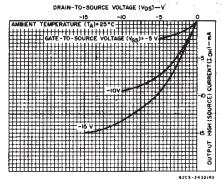


Fig. 6 - Minimum p-channel output high (source) current characteristics.

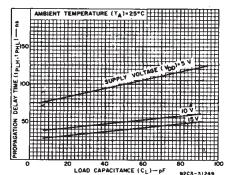


Fig. 7 — Typical propagation delay time $(Q_n \text{ to } Q_n+1)$ as a function of load capacitance.

CD4060B Types

DYNAMIC ELECTRICAL CHARACTERISTICS at T $_{A}$ = 25°C, Input t $_{r}$, t $_{f}$ = 20 ns, C $_{L}$ = 50 pF, R $_{L}$ = 200 k Ω

			<u> </u>	- 50 рг, г		
CHARACTERISTIC	TEST CONDITIONS			LIMITS		UNITS
	CONDITIONS	V _{DD} (V)	MIN.	TYP.	MAX.	011110
Input-Pulse Operation						1.
Propagation Delay		5	_	370	740	
Time, φ[to Q4 Out;		10	_	150	300	
tPHL, tPLH		15	_	100	200	
Propagation Delay		5	_	100	200	
Time, Q_n to Q_{n+1} ;		10		50	100	
tPHL, tPLH		15	-	40	80	
Transition Time,		5	-	100	200	
THL, TLH		10	. –	50	100	ns
		15		40	80	
Min. Input-Pulse	f = 100 l-U-	5	_	50	100	
Width, t _W	f = 100 kHz	10		20	40	
		15	_	15	30	
Input-Pulse Rise & Fall		5				
Time, t _{rø} , t _{fø}		10] (J nlimited	ł	
		15	. [.			
Max. Input-Pulse		5	3.5	7	-	
Frequency, for (External pulse)		10	8	16	_	MHz
source)		15	12	24	_	
Input Capacitance, C ₁	Any Ing	out	_	5	7.5	pF
Reset Operation						
Propagation Delay		5	1 -	180	360	
Time, tPHL		10	_	80	160	
		15		50	100	ns
Minimum Reset		5	_	60	120	
Pulse Width, t _W		10		30	60	
		15	-	20	40	

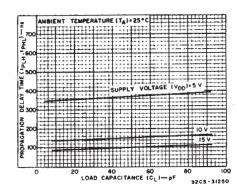


Fig. 8 — Typical propagation delay time ($\phi_{\rm j}$ to $\Omega_{\rm 4}$ Output) as a function of load capacitance.

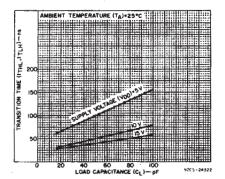


Fig. 9 — Typical transition time as a function of load capacitance.

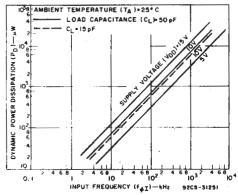


Fig. 10 — Typical dynamic power dissipation as a function of input frequency.

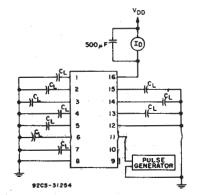


Fig. 11 - Dynamic power dissipation test circuit.

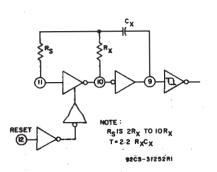


Fig. 12 - Typical RC circuit.

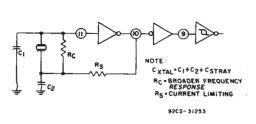


Fig. 13 - Typical crystal circuit.

DYNAMIC ELECTRICAL CHARACTERISTICS at T_A = 25°C, Input t_r , t_f = 20 ns, C_L = 50 pF, R_L = 200 k Ω [cont'd]

				LIMITS		
CHARACTERISTIC	CONDITIONS	V _{DD} (V)	Min.	Тур.	Max.	UNITS
RC Operation						
Variation of Fre-	C _X = 200 pF,	5		23±10%	_	
quency (Unit-to-Unit)	$R_S = 560 \text{ k}\Omega$,	10	1	24±10%	_	
quency (Oint-to-Oint)	$R_X = 50 \text{ k}\Omega$	15	144	25±10%		
Variation of Fre-	C _X = 200 pF,	EV += 10 V		1.5		kHz
quency with voltage	$R_S = 560 \text{ k}\Omega$,	5V to 10 V		1.5		
change (Same Unit)	R _X = 50 kΩ	10V to 15V		0.5	_	
R _X max.	C _X = 10 μF	5	· -		20	
	= 50 μF	10	-	_	20	МΩ
	= 10 μF	15		_	10	
C _X max.	R _X = 500 kΩ	5	_	_	1000	
	= 300 kΩ	10	_	<u> </u>	50	μF
	= 300 kΩ	15		_	50	
Maximum Oscillator	$R_X = 5 k\Omega$ $R_S = 30 k\Omega$	10	530	650	810	kHz
Frequency*	C _X = 15 pF	15	690	800	940	KIIZ
Drive Current at						
Pin 9 (For Oscillator		i				
Design)	V _O = 0.4 V	5	0.16	0.35		
lor		10	0.42	0.8	_	
 	= 1.5 V	15	1	2	-	mA
	V _O = 4.6 V	5	-0.16	-0.35		
[†] ОН	= 9.5 V	10	-0.42	0.8	-	
	= 13.5 V	15	-1	-2	_	

^{*}RC oscillator applications are not recommended at supply voltages below 7 V for $R_{\mbox{\scriptsize X}} < 50~k\Omega_{\star}$

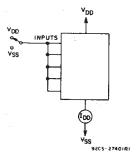


Fig. 14 - Quiescent device current.

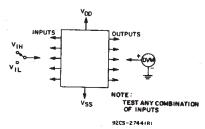


Fig. 15 - Input voltage.

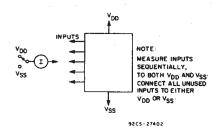
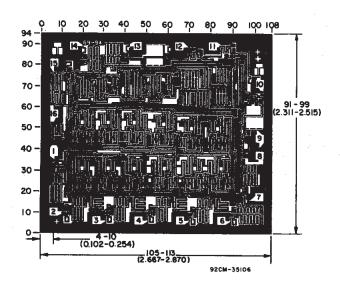
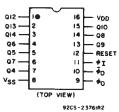


Fig. 16 - Input current.







Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10⁻³ inch).

Chip dimensions and pad layout for CD4060B



15-Oct-2009 www.ti.com

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
CD4060BE	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD4060BEE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD4060BF	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type
CD4060BF3A	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type
CD4060BF3AS2534	OBSOLETE	CDIP	J	16		TBD	Call TI	Call TI
CD4060BM	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4060BM96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4060BM96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4060BM96G4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4060BME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4060BMG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4060BMT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4060BMTE4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4060BMTG4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4060BNSR	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4060BNSRE4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4060BNSRG4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4060BPW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4060BPWE4	ACTIVE	TSSOP PW 16 90 Green (RoHS & CU NIPDAU no Sb/Br)		CU NIPDAU	Level-1-260C-UNLIM			
CD4060BPWG4	ACTIVE	TSSOP	TSSOP PW 16 90 Green (RoHS & CU NIPDAU no Sb/Br)		Level-1-260C-UNLIM			
CD4060BPWR	ACTIVE	TSSOP	PW 16 2000 Green (RoHS & CU NIPDAU no Sb/Br)		CU NIPDAU	Level-1-260C-UNLIM		
CD4060BPWRE4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4060BPWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

(1) The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.



PACKAGE OPTION ADDENDUM

www.ti.com 15-Oct-2009

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.



TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

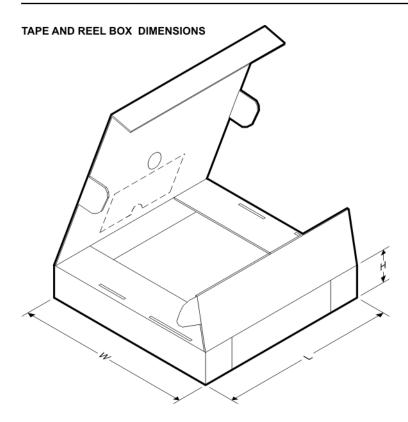
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD4060BM96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD4060BNSR	SO	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
CD4060BPWR	TSSOP	PW	16	2000	330.0	12.4	7.0	5.6	1.6	8.0	12.0	Q1





*All dimensions are nominal

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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD4060BM96	SOIC	D	16	2500	333.2	345.9	28.6
CD4060BNSR	SO	NS	16	2000	346.0	346.0	33.0
CD4060BPWR	TSSOP	PW	16	2000	346.0	346.0	29.0

PW (R-PDSO-G**)

14 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



D (R-PDS0-G16)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.
- Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.
- E. Reference JEDEC MS-012 variation AC.



D(R-PDSO-G16)



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Refer to IPC7351 for alternate board design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC—7525
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.







4-Feb-2021

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CD4060BE	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD4060BE	Samples
CD4060BEE4	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD4060BE	Samples
CD4060BF	ACTIVE	CDIP	J	16	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD4060BF	Samples
CD4060BF3A	ACTIVE	CDIP	J	16	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD4060BF3A	Samples
CD4060BM	ACTIVE	SOIC	D	16	40	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4060BM	Samples
CD4060BM96	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4060BM	Samples
CD4060BMG4	ACTIVE	SOIC	D	16	40	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4060BM	Samples
CD4060BMT	ACTIVE	SOIC	D	16	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4060BM	Samples
CD4060BNSR	ACTIVE	SO	NS	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4060B	Samples
CD4060BPW	ACTIVE	TSSOP	PW	16	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM060B	Samples
CD4060BPWR	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM060B	Samples
CD4060BPWRE4	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM060B	Samples
CD4060BPWRG4	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM060B	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".





4-Feb-2021

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF CD4060B, CD4060B-MIL:

Catalog: CD4060B

Military: CD4060B-MIL

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

All difficusions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD4060BM96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD4060BNSR	SO	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
CD4060BPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD4060BM96	SOIC	D	16	2500	333.2	345.9	28.6
CD4060BNSR	SO	NS	16	2000	853.0	449.0	35.0
CD4060BPWR	TSSOP	PW	16	2000	853.0	449.0	35.0

14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



D (R-PDS0-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





SMALL OUTLINE PACKAGE



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



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